Wideband, Microwave **Monolithic Amplifier**



5 to 20 GHz **50**Ω



CASE STYLE: DQ849

The Big Deal

- •Surface Mount Amplifier up to 20 GHz
- Integrated matching, DC Blocks and bias circuits
- High Reverse Isolation

Product Overview

The Mini-Circuits AVA-24+ is a surface mount, microwave amplifier and fully integrated gain block up to 20 GHz. It is packaged in Mini-Circuits industry standard 3x3 mm MCLP (QFN) package, which provides excellent RF and thermal performance. The AVA-24+ integrates the entire matching network with the majority of the bias circuit inside the package, reducing the need for complicated external circuits. This approach makes the AVA-24+ extremely flexible and enables simple, straightforward use.

NON-CATALOG

Key Features

Feature	Advantages
Wideband, 5 to 20 GHz	Broad frequency range supports a wide array of applications from microwave radio and radar , to military communications and countermeasures.
Excellent Gain Flatness	Typical ± 0.8 dB gain flatness across the entire frequency range minimizes the need for external equalizer networks making it a great fit for instrumentation and EW applications.
High Isolation	With reverse isolation of 37 dB (25 dB directivity), the AVA-24+ is an excellent choice for buffering broadband circuits. It is an ideal LO driver amplifier and provides designers system flexibility and margin when integrating cascaded RF components.
Manufacturability	MSL1 and ESD Class1A (HBM) ratings minimize special handling on production lines.

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Wideband, Microwave **Monolithic Amplifier**

5-20 GHz

Product Features

- Gain, 12.3 dB typ. & Flatness, ±0.8 dB
- Output Power, up to +18.3 dBm typ.
- Excellent isolation, 37 dB typ.
- Single Positive Supply Voltage, 5V
- Integrated DC blocks, Bias-Tee & Microwave bypass capacitor
- Unconditionally Stable
- Aqueous washable; 3mm x 3mm SMT package

Typical Applications

- Military EW and Radar
- DBS
- Wideband Isolation amplifier
- Microwave point-to-point radios
- Satellite systems



CASE STYLE: DQ849 PRICE: Contact Sales Dept.

+RoHS Compliant The +Suffix identifies RoHS Compliance. See our web site for RoHS Compliance methodologies and qualifications

General Description

AVA-24+ is a wideband medium power monolithic amplifier with outstanding gain flatness up to 20 GHz. It is manufactured using PHEMT* technology and is unconditionally stable. Its outstanding isolation enables it to be used as a wideband isolation amplifier or buffer amplifier in a variety of microwave systems.

simplified schematic and pad description





Function	Pad Number	Description (See Application Circuit, Fig. 2)				
RF-IN	2	RF input pad				
RF-OUT	5	RF output pad				
DC	8(V _{D1}), 7 (V _{D2})	DC power supply				
GND	paddle in center of bottom	Connected to ground				
NOT USED	1,3,4,6	No internal connection; recommended use: per PCB Layout PL-328				
RF-OUT DC GND NOT USED	5 8(V _{D1}), 7 (V _{D2}) paddle in center of bottom 1,3,4,6	RF output pad DC power supply Connected to ground No internal connection; recommended use: per PCB Layout PL-328				

*Pseudomorphic High Electron Mobility Transistor.

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REV. A M132481 AVA-24+ ED-13817 MCL NY 130516 Page 2 of 5

Wideband Monolithic PHEMT MMIC Amplifier



Parameter	Condition (GHz)	Min.	Тур.	Max.	Units	
Frequency Range		5.0		20.0	GHz	
DC Voltage (Vp1, Vp2)			5.0		V	
DC Current (Ip1+Ip2)			134	145	mA	
	5.0		12.4			
	8.0	10.0	12.7			
	10.0	10.0	12.4			
Coin	12.0		12.0		dB	
Gain	14.0		11.7		UD UD	
	16.0		12.6			
	18.0	10.0	12.6			
	20.0	9.0	11.5			
	5.0		12.7			
	8.0	10.0	25.7			
	10.0 10.0 17.9					
Input Return Loss	12.0		12.4		dB	
	14.0	10.0	11.3			
	16.0	10.0	15.8			
	18.0		11.7			
	20.0		16.9			
	5.0	10.0	30.0			
	10.0	10.0	25.0			
	12.0	10.0	14.3			
Output Return Loss	14.0		13.6		dB	
	16.0	10.0	20.3			
	18.0	10.0	19.0			
	20.0		11.5			
	5.0		26.2			
	8.0		26.3			
	10.0		26.5		- Dec	
Output IDO	12.0		26.3			
	14.0		26.0		dBm	
	16.0		25.4			
	18.0		24.5			
	20.0		23.8			
	5.0		18.8			
	8.0		18.7			
	10.0 16.0 18.6					
Output Power @ 1 dB compression	12.0		18.7		dBm	
	14.0		18.5			
	16.0		18.0			
	18.0		17.4			
	5.0		7.0			
	8.0		63			
	10.0		5.6			
Noise Figure	12.0		6.5		dB	
	14.0		6.5			
	16.0		6.1			
	18.0		6.1			
	20.0		6.7			
Directivity (Isolation-Gain)			25.0		dB	
DC Current Variation vs. Temperature (2)			-0.087		mA/°C	
Thermal Resistance			47		°C/W	

Electrical Specifications⁽¹⁾ at 25°C, Zo=50Ω, (refer to characterization circuit, Fig. 1)

Absolute Maximum Ratings⁽³⁾

	-			
Parameter	Ratings			
Operating Temperature (4)	-40°C to 85°C			
Storage Temperature	-55°C to 100°C			
Channel Temperature	160°C			
DC Voltage (Pad 7,8)	5.5V			
Voltage (Pads 2, 5)	10V			
Power Dissipation	860 mW			
DC Current (Pad 7+8)	160mA			
Input Power	20 dBm			

(1) Measured on Mini-Circuits Characterization test fixture TB-547-1+

- See Characterization Test Circuit (Fig. 1) ⁽²⁾ (Current at 85°C Current at -45°C)/130 ⁽³⁾ Permanent damage may occur if any of these limits are exceeded.

These maximum ratings are not intended for continuous normal operation. ⁽⁴⁾ Defined with reference to ground pad temperature.

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Characterization Test Circuit



Fig 1. Block Diagram of Test Circuit used for characterization. (DUT soldered on Mini-Circuits Characterization Test Board TB-547-1+) Gain, Output power at 1dB compression (P1dB), Noise Figure, Output IP3 (OIP3) are measured using Agilent's N5242A PNA-X microwave network analyzer.

Conditions:

1. Gain: Pin=-25 dBm

 $C \pm .004$

G±.003 TYP

F±.002

INDEX

OPTIONAL H TYP

- 2. Output IP3 (OIP3): Two tones, spaced 1 MHz apart, -10 dBm/tone at output.
- 3. Vs adjusted for 5V at device (V_{D1} and V_{D2}), compensating loss of bias lines.



Recommended Application Circuit

(refer to evaluation board for PCB Layout and component values)

Fig 2. Recommended Application Circuit

Outline Drawing PCB Land Pattern A±.010→ Ν B±.010 INDEX 00

SEATING

PADDLE

J±.004 TYP

PLANE

E±.002

K±.003 TYP



Suggested Layout, Tolerance to be within $\pm .002$

TYF

TYF

Outline Dimensions (inch)

D REF

	、,								
	J	н	G	F	E	D	С	В	Α
	.016	.046	.012	.067	.067	.008	.035	.118	.118
	0.41	1.17	0.30	1.70	1.70	0.20	0.89	3.00	3.00
wt	Т	S	R	Q	Р	Ν	М	L	К
	041	061	067	031	012	067	1/18	1/0	026
grams	.041	.001	.007	.031	.012	.007	. 140	. 140	.020
grams 0.02	1.041	1.55	1.70	0.79	0.30	1.70	3.76	3.76	0.66

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Product Marking



ESD Rating

Human Body Model (HBM): 1A (250 to <500V) in accordance with ANSI/ESD STM 5.1 - 2001

Machine Model (MM): M1 (<100V) in accordance with ANSI/ESD STM5.2-1999; passes 25V

MSL Rating

Moisture Sensitivity: MSL1 in accordance with IPC/JEDEC J-STD-020D





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